

## Sensors Unlimited: LC/LSC Series



# Extended wavelength InGaAs linear photodiode arrays

High-speed LC/LSC Series InGaAs photodiode arrays for broad wavelength ranges and multichannel spectrometer designs.

#### **BENEFITS**

- Autozero reduction of pixel variation and dark current
- Wavelength ranges of 0.8 to 2.6 μm
- Max lps 91KHz (LC); Max lps 15.5KHz (LSC)
- Four full well capacity options
- 25 μm or 50 μm pitch 1 in or 1/2 in array
- Pixel heights of 25 μm, 250 μm or 500 μm
- Anti-blooming to prevent charge overflow from saturated pixels
- Digital serial input for mode control
- Selectable bandwidth circuit
- ESD resistant
- Integrate While Read for minimum overhead

The LC/LSC Series of InGaAs linear arrays are offered in configurations with 256, 512, and 1024 elements, featuring pixel pitches of 25  $\mu$ m or 50  $\mu$ m, and pixel heights of 25  $\mu$ m, 250  $\mu$ m, and 500  $\mu$ m. These arrays support various wavelength ranges: a standard range of 0.8 to 1.7  $\mu$ m, a shorter range of 0.8 to 1.45  $\mu$ m, and extended ranges of 1.1 to 2.2  $\mu$ m and 1.1 to 2.6  $\mu$ m.

Anti-blooming protection prevents charge flow from saturated pixels, allowing for increased dynamic range and image fidelity. An autozero function reduces dark current and non-uniformity, thereby extending the detector's operational range to higher temperatures and longer exposure times.

These photodetector arrays are hybridized with Sensor Unlimited Inc.'s (SUI) proprietary CMOS readoutintegrated circuits (ROICs), ensuring maximum noise immunity and sensitivity. Optimal ROIC performance requires minimal circuitry, needing only one analog supply and three digital control lines. Four separate gains are selectable with a serial input.

The arrays, renowned for their durability and reliability are available with either a one- or two-stage thermoelectric cooler for temperature stabilization and monitoring.

#### **Applications**

- FTIR/NIR interferometry
- NIR spectroscopy
- Biomedical analysis
- Plastic recycling
- Industrial process control

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#### **Electrical inputs**

| Parameter/description                | Unit | Min. | Nom. | Max.            |
|--------------------------------------|------|------|------|-----------------|
| Power supply voltage VDD             | V    | 4.90 | 5.00 | 5.25            |
| Power supply voltage V <sub>5S</sub> | V    |      | 0    |                 |
| Digital inputs clocks, high          | V    |      | 5.00 | V <sub>DD</sub> |
| Digital inputs clocks, low           |      |      | Vss  | 0.8             |
| Pixel clock frequency                | MHz  | 0.01 |      | 12.5            |

#### **Pixel performance**

| Feedback<br>capacitor | Typical<br>gain | Typical<br>capacity | Typical<br>read<br>noise <sup>1</sup> | Typical<br>dynamic<br>range |
|-----------------------|-----------------|---------------------|---------------------------------------|-----------------------------|
| .01 pF                | 1.6 μV/e        | 1.25 Me             | 800 e RMS                             | 1700:1                      |
| 1.0 pF                | 160 nV/e        | 12.5 Me             | 1 ke RMS                              | 4300:1                      |
| 10.0 pF               | 16 nV/e         | 125 Me              | 10 ke RMS                             | 5000:1                      |
| 20.0 pF               | 8 nV/e          | 250 Me              | 10 ke RMS                             | 5000:1                      |

<sup>&</sup>lt;sup>1</sup>Largest photodiode, autozero off.

#### Linear array comparison table (representative values)

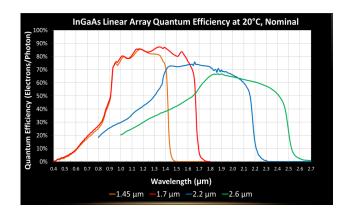
| Material<br>type | Dark<br>current | 50% QE<br>cut-on λ (μm) | 50% QE<br>cut-off λ (μm) | Peak<br>λ (μm) |
|------------------|-----------------|-------------------------|--------------------------|----------------|
| 1.45 μm          | 1.3 pA          | 0.91                    | 1.415                    | 1.17           |
| 1.7 μm           | 2.3 pA          | 0.91                    | 1.65                     | 1.36           |
| 2.2 μm           | 10 nA           | 1.3                     | 2.155                    | 1.67           |
| 2.6 μm           | 100 nA          | 1.64                    | 2.41                     | 1.84           |

#### Absolute maximum ratings

| Parameter  | Unit | Min. | Тур. | Max. |
|--|------|------|------|------|
| Power consumption (VDD=5.00 V), four outputs, high power mode    | mW   |      |      | 350  |
| Power consumption<br>(VDD=5.00 V), one output,<br>low power mode | mW   |      |      | 135  |
| Operating temperature range                                      | °C   | -20  |      | +80  |
| Storage temperature range  | °C   | -20  |      | +85  |

#### Photodiode performance at -20°C

| Photodiode type                             | 2.6 μm, 250 μm |
|---|----------------|
| Inoperable pixels, maximum                  | 5%             |
| Photoresponse nonuniformity (PRNU), maximum | ±10%           |



Specifications subject to change without notice.





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